NSN 5961-01-073-6649

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-073-6649 **Inclosure Material:** Metal **Overall Length:** 0.534 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-63 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.865 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 220.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

NSN 5961-01-073-6649 Transistor - Page 2 of 2



Fiig:

A110a0